High Voltage Power Transistors DPAK For Surface Mount Applications

Designed for line operated audio output amplifier, switchmode power supply drivers and other switching applications.

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- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Lead Formed Version in 16 mm Tape and Reel ("T4" Suffix)
- Electrically Similar to Popular MJE340 and MJE350
- 300 V (Min) VCEO(sus)
- 0.5 A Rated Collector Current

MJD340* PNP MJD350*

*Motorola Preferred Device

SILICON
POWER TRANSISTORS
0.5 AMPERE
300 VOLTS
15 WATTS

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	VCEO	300	Vdc	
Collector–Base Voltage	VCB	300	Vdc	
Emitter–Base Voltage	VEB	3	Vdc	
Collector Current — Continuous — Peak	IC.	0.5 0.75	Adc	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	15 0.12	Watts W/°C	
Total Power Dissipation* @ T _A = 25°C Derate above 25°C	PD	1.56 0.012	Watts W/°C	
Operating and Storage Junction Temperature Range	T _J , T _{Stg}	-65 to +150	°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R ₀ JC	8.33	°C/W
Thermal Resistance, Junction to Ambient*	$R_{\theta JA}$	80	°C/W
Lead Temperature for Soldering Purpose	TL	260	°C

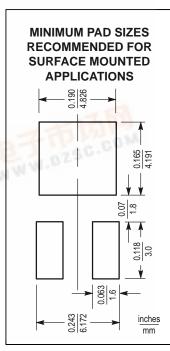
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (1) (I _C = 1 mAdc, I _B = 0)	V _{CEO(sus)}	300		Vdc	
Collector Cutoff Current (V _{CB} = 300 Vdc, I _E = 0)	ІСВО	///	0.1	mAdc	
Emitter Cutoff Current (VBE = 3 Vdc, IC = 0)	I _{EBO}	_	0.1	mAdc	
ON CHARACTERISTICS (1)					
DC Current Gain (I _C = 50 mAdc, V _{CE} = 10 Vdc)	hFE	30	240	_	

^{*} When surface mounted on minimum pad sizes recommended.

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⁽¹⁾ Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$, Duty Cycle $\leq 2\%$.

TYPICAL CHARACTERISTICS

MJD340 300 V_{CE} = 2 V V_{CE} = 10 V 200 hFE, DC CURRENT GAIN T_J = 150°C 100 70 +100°C 50 +25°C 30 20 -55°C 3 5 20 100 200 300 500 I_{C} , COLLECTOR CURRENT (mAdc)

Figure 1. DC Current Gain

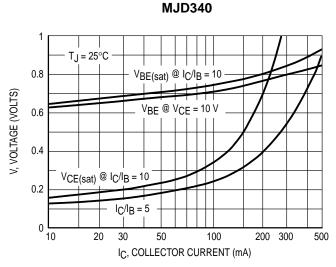
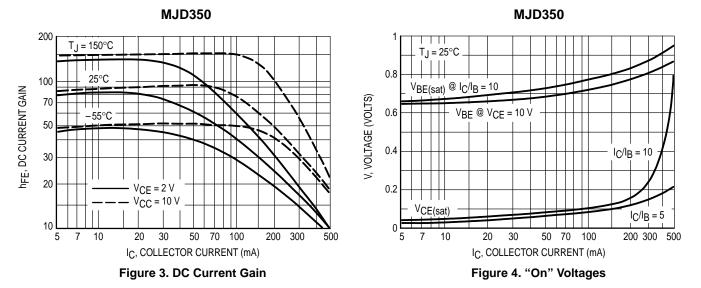


Figure 2. "On" Voltages



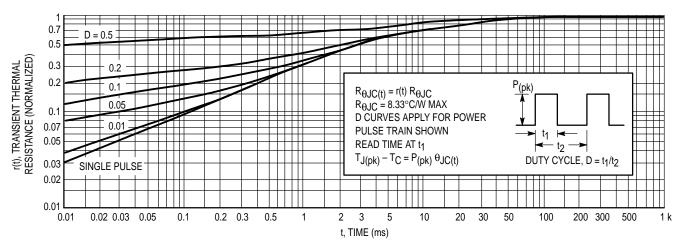


Figure 5. Thermal Response

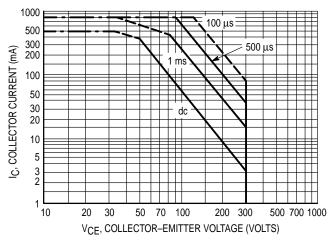


Figure 6. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on $T_{J(pk)} = 150^{\circ}C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 5. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

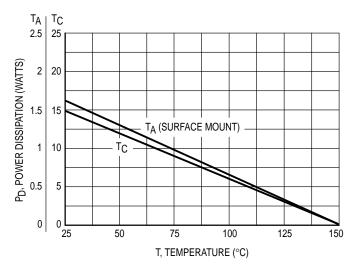
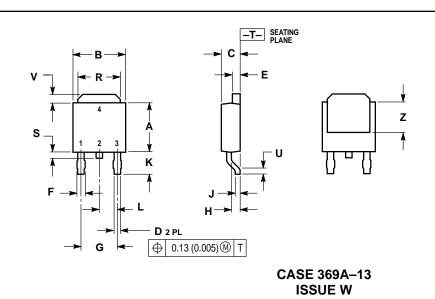


Figure 7. Power Derating

PACKAGE DIMENSIONS



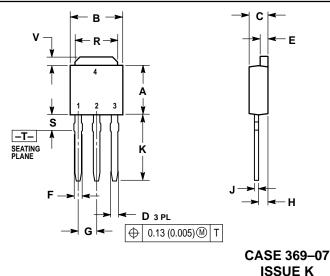
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.250	5.97	6.35	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.033	0.040	0.84	1.01	
F	0.037	0.047	0.94	1.19	
G	0.180 BSC		4.58 BSC		
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.102	0.114	2.60	2.89	
L	0.090 BSC		2.29	BSC	
R	0.175	0.215	4.45	5.46	
S	0.020	0.050	0.51	1.27	
U	0.020		0.51	_	
٧	0.030	0.050	0.77	1.27	
Z	0.138		3.51		

PIN 1. BASE

- 2. COLLECTOR
- **EMITTER**
- COLLECTOR



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Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.175	0.215	4.45	5.46
S	0.050	0.090	1.27	2.28
٧	0.030	0.050	0.77	1.27

STYLE 1:

COLLECTOR EMITTER

COLLECTOR

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How to reach us: USA/EUROPE: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki, 6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE (602) 244-6609 INTERNET: http://Design-NET.com

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298